



DB101S THRU DB107S

SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIERS

Voltage Range - 50 to 1000 Volts Current - 1.0 Ampere

DBS	FEATURES
<p>Technical drawing showing dimensions for DBS bridge rectifier:</p> <ul style="list-style-type: none"> Top view: .047(1.2) x .037(0.95) lead spacing; .256(6.5) x .236(6.0) case width; .327(8.3) x .295(7.5) bridge width; .406(10.3) x .391(10.0) case length; .140(0.35) x .008(0.2) lead thickness. Side view: .326(8.3) x .295(7.5) bridge height; .106(2.70) x .008(2.15) case height; .055(1.4) x .047(1.2) lead height. Bottom view: .205(5.2) x .197(5.0) lead spacing. 	<ul style="list-style-type: none"> ◆ Ideal for printed circuit board ◆ Reliable low cost construction utilizing molded plastic technique ◆ High temperature soldering guaranteed: ◆ 250* / 10 seconds / 0.375"(9.5mm) led length at 5 lbs., (2.3kg)tension ◆ Small size, simple installation Leads solderable per MIL-STD-202, Method 208 ◆ High surge current capability
	MECHANICAL DATA
	<p>Case: Molded plastic body Terminals: Plated leads solderable per MIL-STD-750, Method 2026 Polarity: Polarity symbols marked on case Mounting Position: Any Weight: 0.02 ounce, 0.4 grams</p>

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25* ambient temperature unless otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, For capacitive load derate current by 20%.

	SYMBOLS	DB 101S	DB 102S	DB 103S	DB 104S	DB 105S	DB 106S	DB 107S	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	VOLTS
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	VOLTS
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	VOLTS
Maximum average forward rectified current at $T_A=40^*$	$I_{F(AV)}$	1.0							Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							Amps
Maximum instantaneous forward voltage drop per bridge element at 1.0A	V_F	1.1							Volts
Maximum DC reverse current at rated DC blocking voltage $T_A=25^*$	I_R	10							μA
$T_A=125^*$		500							μA
I^2t Rating for Fusing ($t < 8.3ms$)	I^2t	3.75							A^2s
Operating temperature range	T_J	-55 to +150							$^{\circ}C$
storage temperature range	T_{STG}	-55 to +150							$^{\circ}C$

Note: 1. Measured at 1.0MHz and applied reverse voltage of 4.0V DC

2. Thermal resistance from junction to ambient mounted on P.C.B

with 0.5*0.5"(13*13mm) copper pads.



RATINGS AND CHARACTERISTIC CURVES DB101S THRU DB107S

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FIG.1-FORWARD CURRENT DERATING CURVE

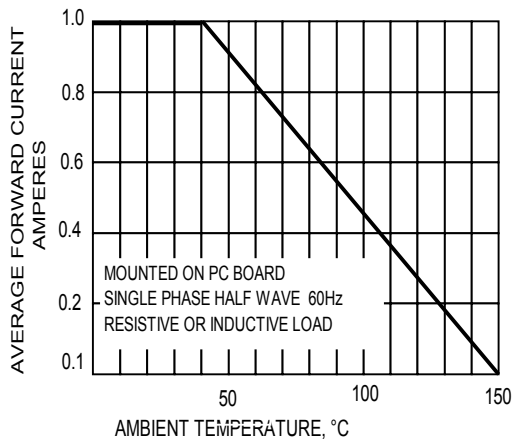


FIG.2-MXIMUM NON-REPETITIVE SURGE CURRENT

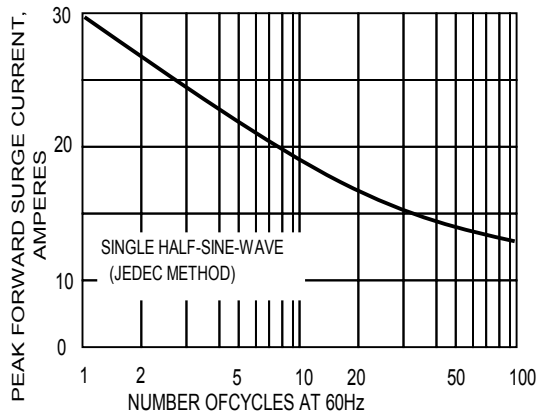


FIG.3-TYPICAL JUNCTION CAPACITANCE

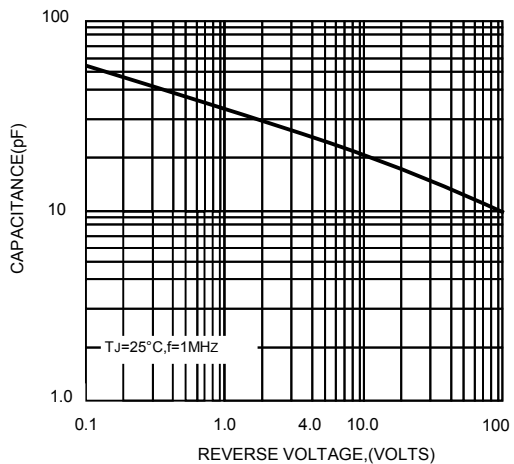


FIG.4-TYPICAL FORWARD CHARACTERISTICS

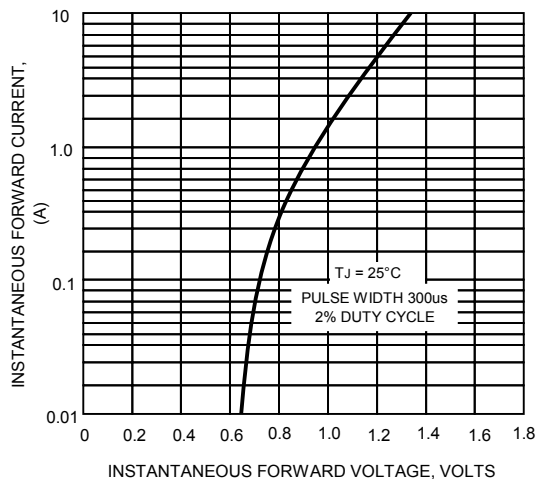


FIG.5-TYPICAL REVERSE CHARACTERISTICS

